# NSN 5961-01-073-6074

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## **Inclosure Material:**

Metal

## **Overall Length:**

Between 0.215 inches and 0.320 inches

# Mounting Facility Quantity:

1

#### Internal Configuration:

Junction contact

## Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-60

#### **Mounting Method:**

Threaded stud

Features Provided:

Hermetically sealed case

#### **Overall Width Across Flats:**

Between 0.424 inches and 0.437 inches

#### Thread Size:

0.190 inches

## Semiconductor Material:

Silicon

# Voltage Rating In Volts Per Characteristic:

65.0 breakdown voltage, collector-to-base, emitter open and 30.0 breakdown voltage, collector-to-emitter, base open and 4.0 breakdown voltage, emitter-to-base, collector open

## **Current Rating Per Characteristic:**

Between 1.50 amperes source cutoff current and 4.50 amperes source cutoff current

## **Power Rating Per Characteristic:**

30.0 watts small-signal input power, common-collector

## **Special Features:**

Junction pattern arrangement: npn

## Test Data Document:

49956-584448 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.;

excludes any specification, standard or other document that may be referenced in a basic governing drawing)

#### **Thread Series Designator:**

Unf

# **Terminal Type And Quantity:**

3 pin

Shelf Life:

N/a

Unit Of Measure:

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## Demilitarization:

No

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